

FEATURES/BENEFITS

- 5V tolerant inputs and outputs
- Bus Hold feature holds last active state during 3-state operation
- $10\mu A$ I_{CCQ} quiescent power supply current
- Hot insertable
- 2.0V–3.6V V_{CC} supply operation
- $\pm 24mA$ balanced output drive
- Power down high impedance inputs and outputs
- Input hysteresis for noise immunity
- Meets or exceeds JEDEC Standard 36 specifications
- Multiple power and ground pins for low noise
- Operating temperature range:
–40°C to 85°C
- Latch-up performance exceeds 500mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V
- Packages available:
 - 56-pin TSSOP
 - 56-pin SSOP

DESCRIPTION

The LVCH16543A is a 16-bit latched bus transceiver with three-state outputs that is ideal for driving address and data buses. Two independent 8-bit D-type latched transceivers are used with separate input and output control to permit independent control of data flow in either direction. The QS74LVCH16543A provides Bus Hold circuitry on the data inputs to retain the last active state during 3-state operation, eliminating the need for external pull-up resistors. The 3.3V LVC family features low power, low switching noise, and fast switching speeds for low power portable applications as well as high-end advanced workstation applications. 5V tolerant inputs and outputs allow this LVC product to be used in mixed 5V and 3.3V applications. Easy board layout is facilitated by the use of flow-through pinouts and byte enable controls provide architectural flexibility for systems designers. To accommodate hot-plug or live insertion applications, this product is designed not to load an active bus when V_{CC} is removed.

Figure 1. Functional Block Diagram

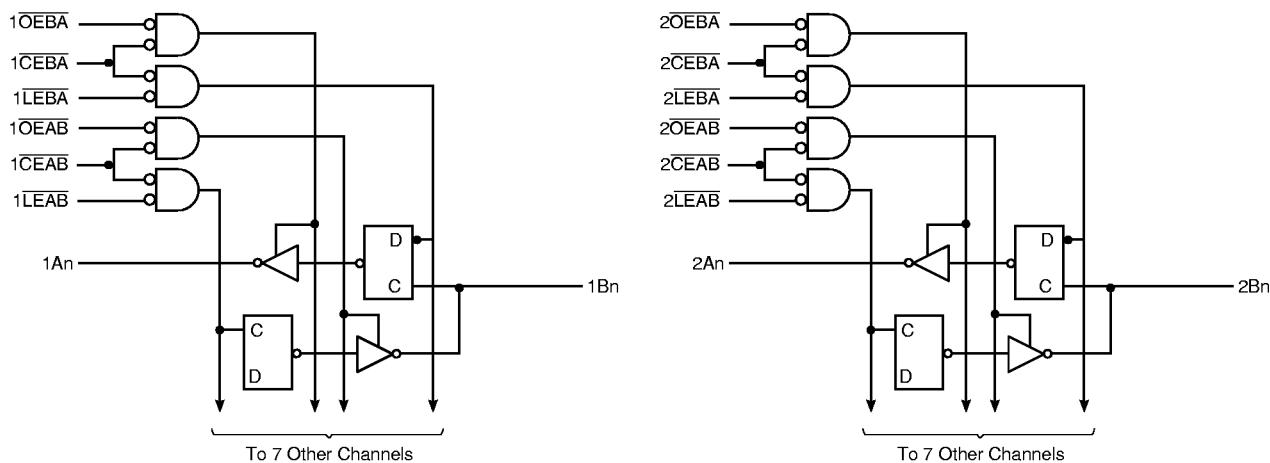


Figure 2. Pin Configuration
(All Pins Top View)

SSOP, TSSOP

1OEAB	1	56	1OEBA
1LEAB	2	55	1LEBA
1CEAB	3	54	1CEBA
GND	4	53	GND
1A1	5	52	1B1
1A2	6	51	1B2
V _{CC}	7	50	V _{CC}
1A3	8	49	1B3
1A4	9	48	1B4
1A5	10	47	1B5
GND	11	46	GND
1A6	12	45	1B6
1A7	13	44	1B7
1A8	14	43	1B8
2A1	15	42	2B1
2A2	16	41	2B2
2A3	17	40	2B3
GND	18	39	GND
2A4	19	38	2B4
2A5	20	37	2B5
2A6	21	36	2B6
V _{CC}	22	35	V _{CC}
2A7	23	34	2B7
2A8	24	33	2B8
GND	25	32	GND
2CEAB	26	31	2CEBA
2LEAB	27	30	2LEBA
2OEAB	28	29	2OEBA

Table 1. Pin Description

Name	Description
xOEAB	A to B Output Enable Inputs (Active LOW)
xOEBA	B to A Output Enable Inputs (Active LOW)
xCEAB	A to B Enable Inputs (Active LOW)
xCEBA	B to A Enable Inputs (Active LOW)
xLEAB	A to B Latch Enable Inputs (Active LOW)
xLEBA	B to A Latch Enable Inputs (Active LOW)
xAx	A to B Data Inputs or B to A 3-State Outputs (Bus Hold Inputs)
xBx	B to A Data Inputs or A to B 3-State Outputs (Bus Hold Inputs)

Table 2. Function Table

Inputs			Status	Latch Buffers	Output
xCEAB	xLEAB	xOEAB	xAx to xBx	xBx	
H	X	X	Storing	High-Z	
X	H	X	Storing	X	
X	X	H	X	High-Z	
L	L	L	Transparent	Current A Inputs	
L	H	L	Storing	Previous* A Inputs	

Notes:

- * = Before xLEAB LOW-to-HIGH Transition
H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
- A-to-B data flow shown: B-to-A flow control is the same, except using xCEBA, xLEBA, xOEBA

Table 3. Absolute Maximum Ratings

Supply Voltage to Ground	-0.5V to 7.0V
DC Output Voltage V_{OUT}	
Outputs HIGH-Z	-0.5V to 7.0V
Outputs Active	-0.5V to $V_{CC} + 0.5V$
DC Input Voltage V_{IN}	-0.5V to 7.0V
DC Input Diode Current with $V_{IN} < 0$	-50mA
DC Output Diode Current	
$V_O < 0$	-50mA
$V_O > V_{CC}$	50mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	$\pm 50mA$
DC Supply Current per Supply Pin	$\pm 100mA$
DC Ground Current per Ground Pin	$\pm 100mA$
T_{STG} Storage Temperature	-65°C to 150°C

Note: Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to this device resulting in functional or reliability type failures.

Table 4. Recommended Operating Conditions

Symbol	Parameter		Min	Max	Unit
V_{CC}	Supply Voltage, Operating		2.0	3.6	V
	Supply Voltage, Data Retention Only		1.5	3.6	
V_{IH}	Input HIGH Voltage	$V_{OL} = 2.7$ to 3.6V	2.0	—	V
V_{IL}	Input LOW Voltage	$V_{CC} = 2.7$ to 3.6V	—	0.8	V
V_{IN}	Input Voltage		0	5.5	V
V_{OUT}	Output Voltage in Active State		0	V_{CC}	V
	Output Voltage in "OFF" State		0	5.5	
I_{OH}	Output Current HIGH $V_{CC} = 3.0$ –3.6V		—	-24	mA
	$V_{CC} = 2.7V$		—	-12	
I_{OL}	Output Current LOW $V_{CC} = 3.0$ –3.6V		—	24	mA
	$V_{CC} = 2.7V$		—	12	
$\Delta t/\Delta v$	Input Transition Slew Rate		—	10	ns/V
T_A	Operating Free Air Temperature		-40	85	°C

Table 5. DC Electrical Characteristics Over Operating RangeIndustrial Temperature Range, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Min	Typ ⁽¹⁾	Max	Unit
V_{OH}	Output HIGH Voltage	$V_{CC} = 2.7\text{V}$, $I_{OH} = -100\mu\text{A}$ $V_{CC} = 2.7\text{V}$, $I_{OH} = -12\text{mA}$ $V_{CC} = 3.0\text{V}$, $I_{OH} = -12\text{mA}$ $V_{CC} = 3.0\text{V}$, $I_{OH} = -24\text{mA}$	$V_{CC} = -0.2$ 2.2 2.4 2.2	— — — —	— — — —	V
V_{OL}	Output LOW Voltage	$V_{CC} = 2.7\text{V}$, $I_{OL} = 100\mu\text{A}$ $V_{CC} = 2.7\text{V}$, $I_{OL} = 12\text{mA}$ $V_{CC} = 3.0\text{V}$, $I_{OL} = 24\text{mA}$	— — —	— — —	0.2 0.4 0.55	V
V_{IK}	Input Clamp Voltage	$V_{CC} = 2.7\text{V}$, $I_{IN} = -18\text{mA}$	—	-0.7	-1.2	V
I_I	Input Leakage Current	$V_I = 0\text{V}$, $V_I = 5.5\text{V}$, $V_{CC} = 3.6\text{V}$	—	—	± 1.0	μA
$ I_{BHL} $	Bus Hold Inputs Overdrive Current ^(2,3)	$V_{CC} = 3.6\text{V}$, $V_{IN} = 0\text{V}$ or $V_{IN} = V_{CC}$	—	—	50	μA
		$V_{CC} = 3.6\text{V}$, $0.8\text{V} < V_{IN} < 2.0\text{V}$	—	—	500 ⁽⁴⁾	
I_{BHH}	Bus Hold Input Sustaining Current	$V_{CC} = 3\text{V}$	$V_{IN} = 2.0\text{V}$	-75	—	μA
I_{BHL}			$V_{IN} = 0.8\text{V}$	75	—	
I_{OZ}	High-Z I/O Leakage	$V_O = 0\text{V}$, $V_O = 5.5\text{V}$, $V_I = V_{IH}$ or V_{IL} , $V_{CC} = 3.6\text{V}$	—	—	± 1.0	μA
I_{OFF}	Power Off Leakage	$V_{CC} = 0\text{V}$, V_I or $V_O = 5.5\text{V}$	—	—	10	μA
I_{CC}	Quiescent Power Supply Current	$V_{CC} = 3.6\text{V}$, $V_{IN} = V_{CC}$ or GND	—	0.1	10	μA
ΔI_{CC}	Quiescent Power Supply Current per Control Inputs at TTL HIGH	$V_{CC} = 3.6\text{V}$, $V_{IN} = V_{CC} - 0.6\text{V}^{(5)}$	—	2.0	3.0	μA
	Quiescent Power Supply Current per Bus Hold Inputs at TTL HIGH	$V_{CC} = 3.6\text{V}$, $V_{IN} = V_{CC} - 0.6\text{V}^{(5)}$	—	75	500	μA

Notes:

1. Typical values are at $V_{CC} = 3.3\text{V}$ and $T_A = 25^\circ\text{C}$.
2. These parameters are guaranteed by characterization, but not production tested.
3. Pins with Bus Hold are identified in the pin description.
4. An external driver must provide at least $|I_{BHL}|$ during transition to guarantee that the Bus Hold input will change state.
5. Per TTL driven input. All other inputs at V_{CC} or GND.

Table 6. Dynamic Switching Characteristics

Symbol	Parameter	Test Conditions			Typ ⁽¹⁾	Unit
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50\text{pF}$, $V_{CC} = 3.3\text{V}$	$V_{IH} = 3.3\text{V}$, $V_{IL} = 0\text{V}$		0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50\text{pF}$, $V_{CC} = 3.3\text{V}$	$V_{IH} = 3.3\text{V}$, $V_{IL} = 0\text{V}$		0.8	V
C_{PD}	Power Dissipation	$C_L = 50\text{pF}$, $f = 10\text{MHz}$, $V_{CC} = 3.3 \pm 0.3\text{V}$	Output Enable		25	pF
			Output Disable		4	

Note:

1. Typical values are at $V_{CC} = 3.3\text{V}$, 25°C ambient.

Table 7. Capacitance⁽¹⁾

Symbol	Pins	Conditions	Typ	Unit
C_{IN}	Input Capacitance	$V_{IN} = 0\text{V}$, $V_{OUT} = 0\text{V}$, $f = 1\text{MHz}$	7.0	pF
$C_{I/O}$	I/O Capacitance	$V_{IN} = 0\text{V}$, $V_{OUT} = 0\text{V}$, $f = 1\text{MHz}$	8.0	pF

Note:

1. Capacitance is characterized but not production tested.

Table 8. Switching Characteristics Over Operating Range

Industrial Temperature Range, $T_A = -40^\circ\text{C}$ to 85°C .

$C_{LOAD} = 50\text{pF}$, $R_{LOAD} = 500\Omega$ unless otherwise noted.

Symbol	Description ⁽¹⁾	$V_{CC} = 3.3 \pm 0.3\text{V}$		$V_{CC} = 2.7\text{V}^{(2)}$		Unit
		Min	Max	Min	Max	
t_{PD}	Propagation Delay Transparent Mode xAx to xBx or xBx to xAx	1.5	5.4	1.5	6.1	ns
	Propagation Delay $x\overline{LEBA}$ to xAx , $x\overline{LEAB}$ to xBx	1.5	6.1	1.5	7.4	ns
t_{EN}	Output Enable Time $x\overline{OEBA}$ or $x\overline{OEAB}$ to xAx or xBx , $x\overline{CEBA}$ or $x\overline{CEAB}$ to xAx or xBx	1.5	6.3	1.5	7.6	ns
t_{DIS}	Output Disable Time ⁽²⁾ $x\overline{OEBA}$ or $x\overline{OEAB}$ to xAx or xBx , $x\overline{CEBA}$ or $x\overline{CEAB}$ to xAx or xBx	1.5	6.3	1.5	6.9	ns
t_{SU}	Setup Time HIGH or LOW xAx or xBx to $x\overline{LEBA}$ or $x\overline{LEAB}$	1.1	—	1.1	—	ns
t_H	Hold Time HIGH or LOW xAx or xBx to $x\overline{LEBA}$ or $x\overline{LEAB}$	1.9	—	1.9	—	ns
t_W	Pulse Width LOW ⁽²⁾	3.3	—	3.3	—	ns
$t_{SK(O)}$	Output Skew ⁽³⁾	—	0.5	—	—	ns

Notes:

1. Minimums guaranteed but not tested. See Test Circuit and Waveforms.
2. Guaranteed by characterization.
3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by characterization but not production tested.

TEST CIRCUIT AND WAVEFORMS

Figure 3. Test Circuit

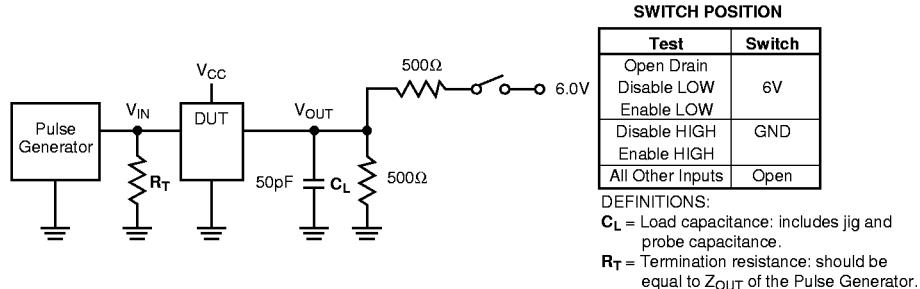


Figure 4. Setup, Hold, and Release Timing

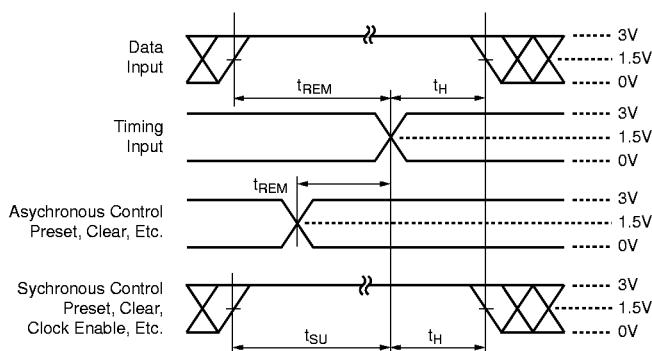


Figure 6. Pulse Width

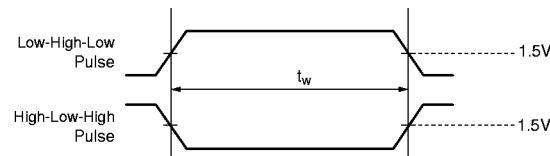


Figure 5. Enable and Disable Timing

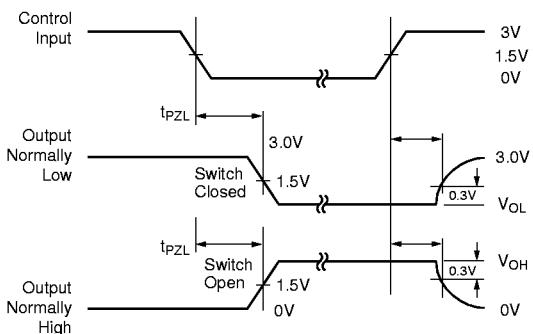
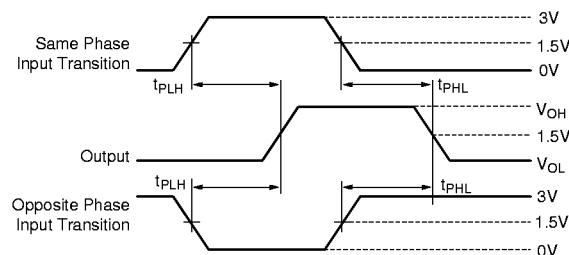


Figure 7. Propagation Delay



Notes:

1. Input Control Enable = LOW and Input Control Disable = HIGH.
2. Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $Z_{OUT} \leq 50\Omega$; $t_F, t_R \leq 2.5\text{ns}$.

ORDERING INFORMATION

